
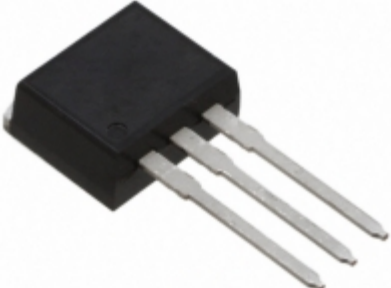
	<h2 style="color: red;">FQI4N90TU</h2> <p>Hersteller-Teilenummer: FQI4N90TU</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 900V 4.2A I2PAK</p> <p>Datenblätter:  FQI4N90TU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4004 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQI4N90TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 900V 4.2A I2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4004 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I ² Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK
Verlustleistung (max)	3.13W (Ta), 140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.2A (Tc)
Rds On (Max) @ Id, Vgs	3.3 Ohm @ 2.1A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQI4N90TU ist neu im Original, Suche FQI4N90TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQI4N90TU Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQI4N90TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQI4P40TU AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 3.5A I2PAK</p>	 <p>FQI4N80 FAIRCHILD FQI4N80 FAIRCHILD</p>	 <p>FQI4P40TU Fairchild/ON Semiconductor MOSFET P-CH 400V 3.5A I2PAK</p>	 <p>FQI4N80TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 3.9A I2PAK</p>
 <p>FQI4N90TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 4.2A I2PAK</p>	 <p>FQI4N80TU Fairchild/ON Semiconductor MOSFET N-CH 800V 3.9A I2PAK</p>	 <p>FQI4N60 Original FQI4N60 Original</p>	 <p>FQI4P40 FSC FQI4P40 FSC</p>

heiße Teile

Mehr

 FQI16N15TU	 FQI17N08L	 FQI17P06TU	 FQI17P06TU	 FQI17P20
 FQI19N10LTU	 FQI19N20TU	 FQI19N20TU	 FQI27N25TU	 FQI27N25TU
 FQI2N50TU	 FQI2NA90	 FQI2P25TU	 FQI2P25TU	 FQI3N25TU
 FQI3N25TU	 FQI3N30TU	 FQI3N30TU	 FQI47P06TU	 FQI47P06TU
 FQI4N20TU	 FQI4N20TU	 FQI4N80TU	 FQI4N80TU	 FQI4N90TU
 FQI50N06	 FQI50N06L	 FQI5N20L	 FQI5N50CTU	 FQI5N50CTU
 FQI5N50TU	 FQI5N60C	 FQI5N60CTU	 FQI5N60CTU	 FQI5N60TU
 FQI6N25TU	 FQI6N40TU	 FQI6N60C	 FQI7N60TU	 FQI7N60TU
 FQI7N80TU	 FQI7N80TU	 FQI7P20TU	 FQI8N25TU	 FQI8N60CTU
 FQI8N60CTU	 FQI9N08L	 FQI9N25C	 FQI9N50C	 FQI9N50CTU

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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